

2SA1576AQ~2SA1576AS
GENERAL PURPOSE TRANSISTORS
PNP SILICON

DESCRIPTION

The 2SA1576AQ~2SA1576AS are available in SC-70 package

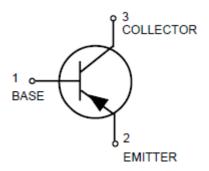
FEATURES

- RoHS Compliant
- Available in SC-70 package

ORDERING INFORMATION

Package Type	age Type Part Number				
	2SA1576AQ				
SC-70	2SA1576AR				
	2SA1576AS				
Note	3,000pcs/ Reel				
AiT provides all RoHS Compliant Products					

PIN DESCRIPTION



REV1.0 - MAR 2013 RELEASED - -1-

ABSOLUTE MAXIMUM RATINGS

V _{CEO} , Collector-Emitter Voltage	-50V
V _{CBO} , Collector-Base Voltage	-60V
V _{EBO} , Emitter-Base Voltage	-6.0V
Ic, Collector Current-Continuous	-150mA
Pc, Collector Power Dissipation	0.15W
T _J , Junction Temperature	150°C
T _{STG} , Storage Temperature	-55°C ~ +150°C

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

 $T_A = 25$ °C, unless otherwise noted.

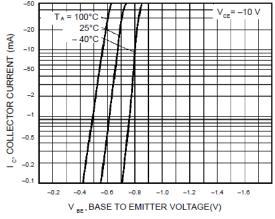
Parameter	Symbol	Characteristic		Min.	Тур.	Max.	Unit
Collector-Emitter Breakdown Voltage	V _{(BR)CEO}	I _C =-1mA		-50	-	•	V
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	I _E =-50μA		-6	-	-	V
Collector-Base Breakdown Voltage	V _{(BR)CBO}	I _C =-50μA		-60	-	-	V
Collector Cutoff Current	Ісво	V _{CB} =-60V		-	-	-0.1	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} =-6V		-	-	-0.1	μA
Collector-Emitter Saturation Voltage	V _{CE(sat)}	I _C /I _B =-50mA/-5mA		-	-	-0.5	V
DC Current Transfer Ratio	h _{FE}	V _{CE} = -6V, I _C = -1mA	Q	120	-	270	
			R	180	-	390	-
			S	270	-	560	
Transition Frequency	f⊤	V _{CB} =-12V, I _E =2mA, f=30MHz		-	140	ı	MHz
Output Capacitance	Cob	V _{CB} =-12 V, I _E =0A, f=1MHz		-	4.0	5.0	pF

REV1.0 - MAR 2013 RELEASED - - 2 -

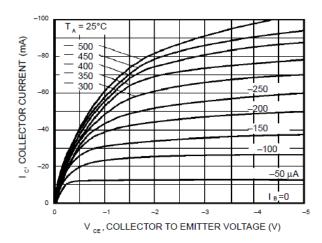


TYPICAL CHARACTERISTICS

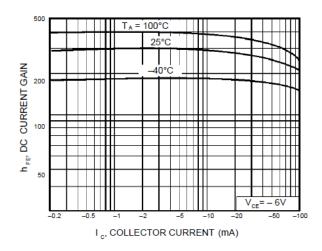
1. Grounded emitter propagation characteristics



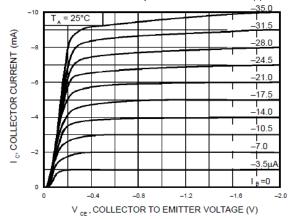
3. Grounded emitter output characteristics(II)



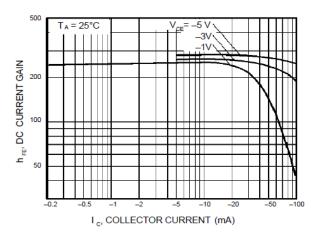
5. DC current gain vs. collector current (II)



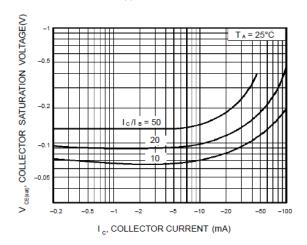
2. Grounded emitter output characteristics(I)



4. DC current gain vs. collector current (I)



. Collector-emitter saturation voltage vs. collector current (I)



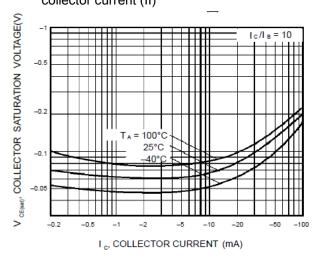
REV1.0 - MAR 2013 RELEASED - - 3 -



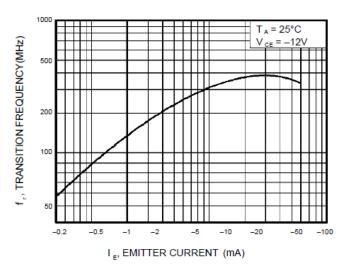
2SA1576AQ~2SA1576AS GENERAL PURPOSE TRANSISTORS

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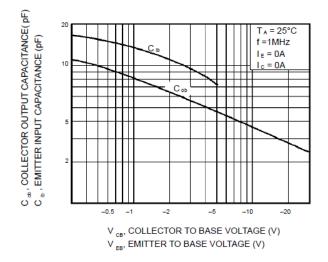
7. Collector-emitter saturation voltage vs. collector current (II)



8. Gain bandwidth product vs. emitter current



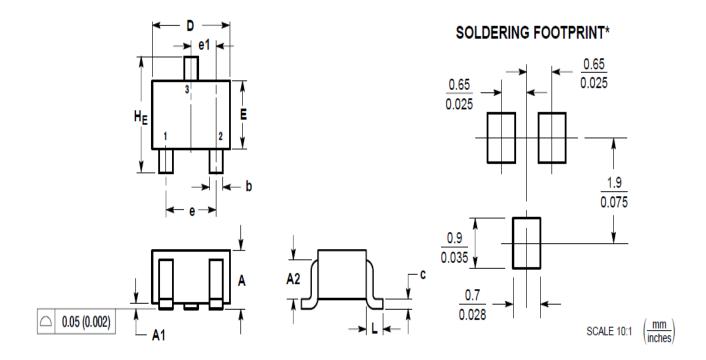
9. Collector output capacitance vs. collector-base voltage Emitter inputcapacitance vs. emitter-base voltage



REV1.0 - MAR 2013 RELEASED --4-

PACKAGE INFORMATION

Dimension in SC-70 Package (Unit: mm)



DIM	MILLIMETERS		INCHES		
	MIN	MAX	MIN	MAX	
Α	0.80	1.00	0.032	0.040	
A1	0.00	0.10	0.000	0.004	
A2	0.7	REF	0.028 REF		
b	0.30	0.40	0.012	0.016	
С	0.10	0.25	0.004	0.010	
D	1.80	2.20	0.071	0.087	
Е	1.15	1.35	0.045	0.053	
е	1.20	1.40	0.047	0.055	
e1	0.65 BSC		0.026 BSC		
L	0.425 REF		0.017 REF		
HE	2.00	2.40	0.079	0.095	

REV1.0 - MAR 2013 RELEASED - - 5 -



2SA1576AQ~2SA1576AS

GENERAL PURPOSE TRANSISTORS PNP SILICON

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REV1.0 - MAR 2013 RELEASED - - 6 -